#### DESCRIPTION

The SPN1024 is the Dual N-Channel enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. This high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage applications such as notebook computer power management and other battery powered circuits where high-side switching, low in-line power loss, and resistance to transients are needed.

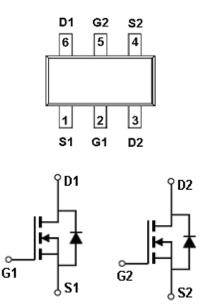
#### APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

#### FEATURES

- N-Channel
  20V/0.65A,RDs(ON)=380mΩ@VGs=4.5V
  20V/0.55A,RDs(ON)=450mΩ@VGs=2.5V
  20V/0.45A,RDs(ON)=800mΩ@VGs=1.8V
- Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- SOT-563 (SC-89-6L) package design

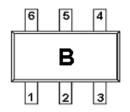
#### PIN CONFIGURATION (SOT-563 / SC-89-6L)



n-channel

n-channel

#### PART MARKING





PIN DESCRIPTION						
Pin	Symbol	Description				
1	S1	Source 1				
2	G1	Gate 1				
3	D2	Drain 2				
4	S2	Source 2				
5	G2	Gate 2				
6	D1	Drain1				

#### **ORDERING INFORMATION**

Part Number	Package	Part Marking		
SPN1024S56RGB	SOT-563	В		

※ SPN1024S56RGB : Tape Reel ; Pb − Free, Halogen - Free

### ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		VDSS	20	V	
Gate –Source Voltage		VGSS	±12	V	
Continuous Drain Current(TJ=150°C)	TA=25°C	In	0.65		
	TA=80°C	– Id	0.45	A	
Pulsed Drain Current		Idm	1.0	А	
Continuous Source Current(Diode Conduction)		Is	0.3	А	
Power Dissipation	TA=25°C	Do	0.35	W/	
	Та=70°С	PD PD	0.19	— W	
Operating Junction Temperature		TJ	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	

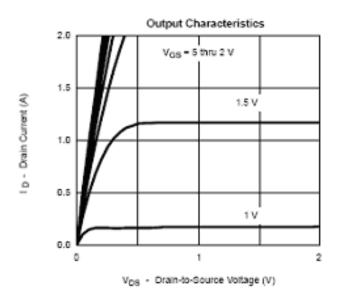


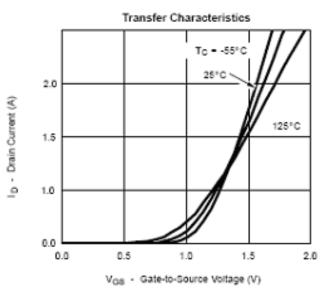
### ELECTRICAL CHARACTERISTICS

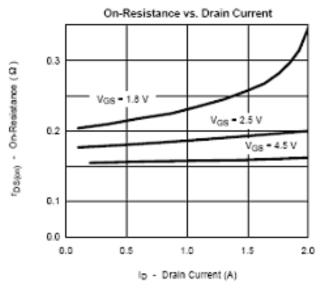
(TA=25°C Unless otherwise noted)

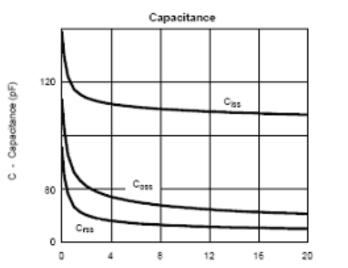
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static		·					
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	20			V	
Gate Threshold Voltage	VGS(th)	VGS(th) VDS=VGS,ID=250uA			1.0	V	
Gate Leakage Current	Igss	VDS=0V,VGS=±12V			100	nA	
Zero Gate Voltage Drain Current		VDS=20V,VGS=0V			1	uA	
	Idss	Vds=20V,Vgs=0V Tj=55°C			5		
On-State Drain Current	ID(on)	VDS≥4.5V,VGS=5V	0.7			А	
	RDS(on)	Vgs=4.5V,Id=0.65A		0.26	0.38		
Drain-Source On-Resistance		Vgs=2.5V,Id=0.55A		0.32	0.45	Ω	
		Vgs=1.8V,Id=0.45A		0.42	0.80		
Forward Transconductance	gfs	Vds=10V,Id=0.4A		1.0		S	
Diode Forward Voltage	Vsd	Is=0.15A,Vgs=0V		0.8	1.2	V	
Dynamic							
Total Gate Charge	Qg	Vds=10V,Vgs=4.5V,		1.2	1.5	nC	
Gate-Source Charge	Qgs	ID=0.6A		0.2			
Gate-Drain Charge	Qgd			0.3			
Turn-On Time	td(on)	$V_{DD}=10V,RL=10\Omega$ ,		5	10	nS	
	tr	ID=0.5A		8	15		
Turn-Off Time	td(off)	Vgen=4.5V,Rg=6Ω		10	18		
	tf	]		1.2	2.8		

#### TYPICAL CHARACTERISTICS





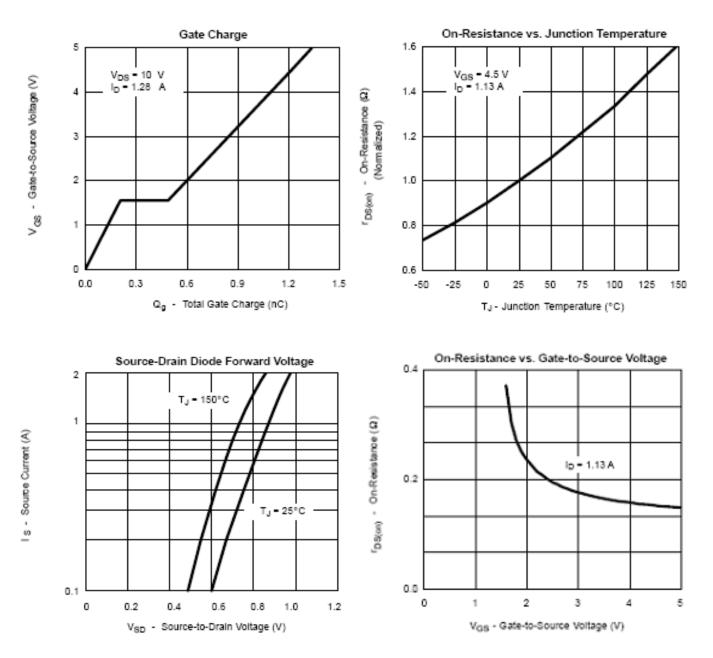




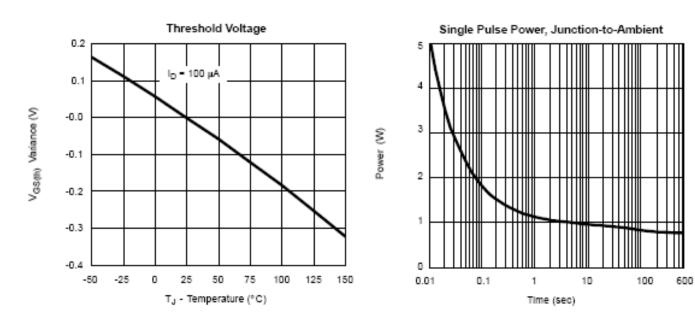
VDS - Drain-to-Source Voltage (V)

2020/04/16 Ver.3

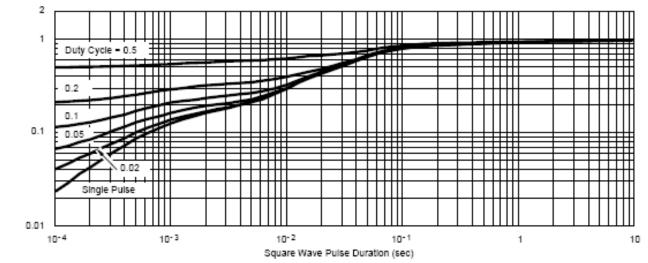
#### TYPICAL CHARACTERISTICS



#### TYPICAL CHARACTERISTICS



Normalized Thermal Transient Impedance, Junction-to-Foot



Normalized Effective Transient Thermal Impedance



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